NSN 5961-01-184-1504

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View Online at https://aerobasegroup.com/nsn/5961-01-184-1504 **Inclosure Material:** Metal **Overall Length:** 1.253 inches **Overall Height:** 0.300 inches **Overall Width:** 0.700 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 80.0 breakdown voltage, collector-to-base, emitter open and 80.0 breakdown voltage, collector-to-emitter, base open and 5.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** 5.00 amperes source cutoff current and 0.50 amperes source cutoff current **Power Rating Per Characteristic:** 20.0 watts small-signal input power, common-collector preset **Transfer Ratio:** 40.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 2 pin and 1 case Shelf Life: N/a

Demilitarization: Yes - demil/mli

Unit Of Measure:

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